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# International IOR Rectifier

Provisional Datasheet

3 Amp

30BQ015

PD - 2.490

## SCHOTTKY RECTIFIER

#### Major Ratings and Characteristics

Characteristics	30BQ015	Units
I <sub>F(AV)</sub> Rectangular waveform	3.0	А
V <sub>RRM</sub>	15	V
I <sub>FSM</sub> @ tp = 5µs sine	650	А
V <sub>F</sub> @ 3.0Apk, T <sub>J</sub> = 75°C	0.30	V
Тј	-55 to 100	°C

#### **Description / Features**

The 30BQ015 surface-mount Schottky rectifier has been designed for applications requiring very low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging and reverse battery protection.

- Small footprint, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long-term reliability





### 30BQ015

#### **Voltage Ratings**

Part number		30BQ015		
V <sub>R</sub> Max. DC Rever	se Voltage (V)	15		
V <sub>RWM</sub> Max. Working P	eak Reverse Voltage (V)	25		

IQR

#### **Absolute Maximum Ratings**

	Parameters	30BQ	Units	Conditions	
I <sub>F(AV)</sub>	Max. Average Forward Current	3.0	А	50% duty cycle @ T <sub>C</sub> = 83°C, rectangular waveform	
		4.0		50% duty cycle @ T <sub>C</sub> = 78°C, rectangular waveform	
I <sub>FSM</sub>	Max. Peak One Cycle Non - Repetitive	650	А	5µs Sine or 3µs Rect. pulse	Following any rated load condition
	Surge Current	95		10ms Sine 0r 6ms Rect. pulse	and with rated V <sub>RRM</sub> applied.
EAS	Non - Repetitive Avalanche Energy	9	mJ	$T_J = 25^{\circ}C, I_{AS} = 0.6A, L = 6.6mH$	
I <sub>AR</sub>	Repetitive Avalanche Current	0.6	А	Current decaying linearly to zero in 1µsec	
				Frequency limited by $T_J$ max. $V_A$ = 1.5 X $V_R$ typical	

### **Electrical Specifications**

Para	meters	30BQ	Units		Conditions
V <sub>FM</sub>	Max. Forward Voltage Drop ①	0.35	V	@ 3.0A	T - 25°C
			V	@ 6.0A	13-23 0
		0.30	V	@ 3.0A	
			V	@ 6.0A	$I_{\rm J} = 75^{\circ}{\rm C}$
I <sub>RM</sub>	Max. Reverse Leakage Current ①	4	mA	$T_J = 25^{\circ}C$	$V_{\rm R}$ = rated $V_{\rm R}$
		50	mA	T <sub>J</sub> = 125°C	
Ст	Max. Junction Capacitance	1120	pF	$V_R = 5V_{DC}$ , (test signal range 100KHz to 1MHz) 25°C	
Ls	Typical Series Inductance	3.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change	10,000	V/µs		
	(Rated V <sub>R</sub> )				

#### **Thermal-Mechanical Specifications**

	Parameters	30BQ	Units	Conditions
TJ	Max.Junction Temperature Range	-55 to 100	°C	
T <sub>STG</sub>	Max. Storage Temperature Range	-55 to 100	°C	
R <sub>thJA</sub>	Max. Thermal Resistance, Junction	12	°C/W	DC operation
	to Ambient			
R <sub>thJL</sub>	Max. Thermal Resistance, Junction	46	°C/W	DC operation
	to Lead 2			
wt	Approximate Weight	0.24	g	
	Case Style	SMC		Similar to DO-214AB

0 Pulse Width < 300 $\mu s,$  Duty Cycle < 2%

② Mounted 1 inch square PCB, thermal probe connected to lead 2mm from package

#### **Refer to the Appendix Section for the following: Appendix D:** Tape and Reel Information — See page 339.